(12) INTERNATIONAL APPLICATION PUBLISHED UNDER THE PATENT COOPERATION TREATY (PCT)

(19) World Intellectual Property Organization

International Bureau



| 1881|| \$111||188|| || 1881|| 1881|| 1891|| 1881|| 1881|| 1881|| 1891|| 1891|| 1891|| 1891|| 1991|| 1991|| 199

(43) International Publication Date 7 October 2004 (07.10.2004)

PCT

(10) International Publication Number WO 2004/086578 A2

(51) International Patent Classification7: H01S 5/183, 5/14

(21) International Application Number:

PCT/GB2004/001285

(22) International Filing Date: 24 March 2004 (24.03.2004)

(25) Filing Language:

English

(26) Publication Language:

English

(30) Priority Data: 0306800.4

24 March 2003 (24.03.2003) GB

(71) Applicant (for all designated States except US): THE UNIVERSITY OF STRATHCLYDE [GB/GB]; Mc-Cance Building, 16 Richmond Street, Glasgow G1 1XQ (GB).

(72) Inventors; and

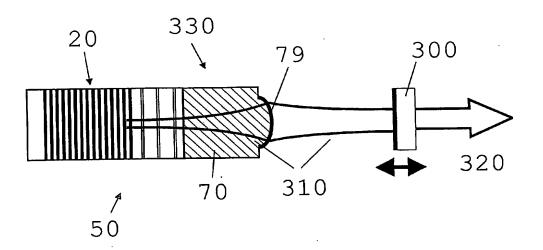
(75) Inventors/Applicants (for US only): CALVEZ. Stephane, Luc, Dominique [FR/GB]; Flat 2/2, 24 Nairn Street, Glasgow G3 8SF (GB). HOPKINS, John-Mark [GB/GB]; Flat 3/1, 52 Albert Ave, Queenspark, Glasgow G42 8RD (GB). BURNS, David [GB/GB]; 2/30 Spears

Wharf, Glasgow G4 9TB (GB). DAWSON, Martin, David [GB/GB]; 57 Balmoral Drive, Bishopton, Renfrewshire PA7 5HR (GB). JEON, Chan Wook [KR/GB]; Flat 5/3, Whistlefield Crt, 2 Canniesburn Rd, Glasgow G61 1PX (GB). CHOI, Hoi Wai [CN/GB]; Flat 3, 11 Princes Terrace, Glasgow G12 9JP (GB).

- (74) Agents: CRITTEN, Matthew, Peter et al.; Abel & Imray, 20 Red Lion Street, London WC1R 4PQ (GB).
- (81) Designated States (unless otherwise indicated, for every kind of national protection available): AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, EG, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NA, NI, NO, NZ, OM, PG, PH, PL, PT, RO, RU, SC, SD, SE, SG, SK, SL, SY, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, YU, ZA, ZM, ZW.
- (84) Designated States (unless otherwise indicated, for every kind of regional protection available): ARIPO (BW, GH, GM, KE, LS, MW, MZ, SD, SL, SZ, TZ, UG, ZM, ZW), Eurasian (AM, AZ, BY, KG, KZ, MD, RU, TJ, TM), European (AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR,

[Continued on next page]

(54) Title: IMPROVEMENTS IN AND RELATING TO VERTICAL-CAVITY SEMICONDUCTOR OPTICAL DEVICES



(57) Abstract: A vertical-cavity device comprises: (a) a chip comprising an active semiconductor layer for providing optical gain; (b) a first mirror arranged on a first side of the active layer; (c) a second mirror arranged on a second side of the active layer, opposite to the first mirror, and forming with at least the first mirror an optically resonant cavity that passes through the active layer in a direction out of the plane of the active layer; (d) a heatspreader for removing heat from the active layer, the heatspreader being arranged inside the cavity and having a first surface adjacent to the chip and a second surface opposite to the first surface, the heatspreader being transparent to light of wavelengths in an operating bandwidth of the device. In addition to removing heat from the active layer, the heatspreader also has one or more further selected property that has a further selected effect on light output from the device.

WO 2004/086578 A2



GB, GR, HU, IE, IT, LU, MC, NL, PL, PT, RO, SE, SI, SK, TR), OAPI (BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG).

For two-letter codes and other abbreviations, refer to the "Guidance Notes on Codes and Abbreviations" appearing at the beginning of each regular issue of the PCT Gazette.

Published:

 without international search report and to be republished upon receipt of that report